

Abstract of the Disclosure:

A circuit is enabled to capacitively drive a memory cell (erasing, programming, and reading) via a capacitance. The capacitance is additionally present and isolates the antenna  
5 from the driver circuit of the memory cell. Charge accumulates on the antenna in the case of a FIB attack. The capacitance prevents the charge from flowing away, so that the voltage thus generated acts on the memory cell, which thus experiences a corresponding alteration of its charge state, which is  
10 detected. The capacitance can be implemented and realized in any conventional manner, such as any arbitrary capacitor structure of the circuit.